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Sensors



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TLE4976-1H TLE4976L

Revision History: 2005-10 V 1.1

Previous Version: 1.0

Page	Subjects (major changes since last revision)
6	Figure 1 Correction of dimensions for package PG-SSO-3-2
15	Figure 8 Correction of dimensions
16	Figure 11 Correction of dimensions
17	Figure 12 Correction of dimensions

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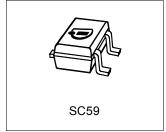
High Precision Hall-Effect Switch with Current Interface

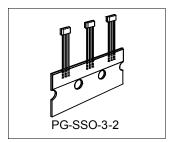
TLE4976-1H TLE4976L

1 Overview

1.1 Features

- 3.0 V to 26 V supply voltage operation
- High sensitivity and high stability of the magnetic switching points
- High resistance to mechanical stress by Active Error Compensation
- Reverse battery protection (– 18 V)
- Superior temperature stability
- Peak temperatures up to 195°C without damage
- Low jitter (typ. 1 µs)
- High ESD performance (± 8 kV HBM)
- Digital output signal with current modulation 6 / 14 mA
- Unipolar version
- SMD package SC59 (SOT23 compatible) -(TLE4976-1H))
- Leaded package PG-SSO-3-2 (TLE4976L)





1.2 Functional Description

The TLE4976-1H and the TLE4976L are integrated circuit Hall-effect sensors designed specifically for highly accurate applications.

Precise magnetic switching points and high temperature stability are achieved by active compensation circuits and chopper techniques on chip.

Туре	Package
TLE4976-1H	SC59
TLE4976L	PG-SSO-3-2



Overview

1.3 Pin Configuration (top view)

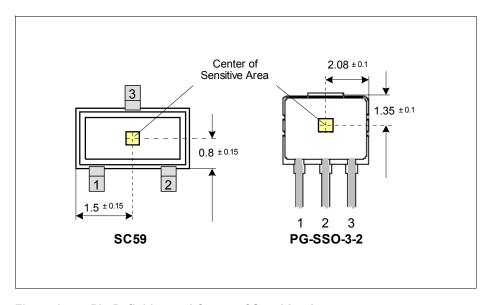


Figure 1 Pin Definition and Center of Sensitive Area

Table 1 Pin Definitions and Functions SC59

Pin No.	Symbol	Function
1	V_{S}	Supply voltage
2	N.C.	No internal connection
3	GND	Ground

Table 2 Pin Definitions and Functions PG-SSO-3-2

Pin No.	Symbol	Function
1	V_{S}	Supply voltage
2	GND	Ground
3	N.C.	No internal connection

General

2 General

2.1 Block Diagram

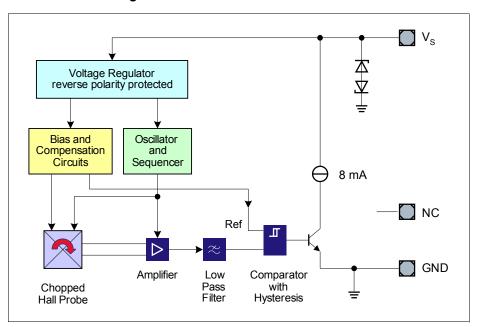


Figure 2 Block Diagram

2.2 Circuit Description

The chopped Hall IC Switch comprises a Hall probe, bias generator, compensation circuits, oscillator, and output transistor.

The bias generator provides currents for the Hall probe and the active circuits. Compensation circuits stabilize the temperature behavior and reduce technology variations.

The Active Error Compensation rejects offsets in signal stages and the influence of mechanical stress to the Hall probe caused by molding and soldering processes and other thermal stresses in the package.

This chopper technique together with the threshold generator and the comparator ensure high accurate magnetic switching points.

The current consumption depends on the switching status.



Maximum Ratings

3 Maximum Ratings

Table 3 Absolute Maximum Ratings $T_i = -40^{\circ}\text{C}$ to 150°C

Parameter	Symbol	Limit Values		Unit	Conditions	
		min.	max.			
Supply voltage	V_{S}	- 18 - 18 - 18	18 24 26	V	$\begin{array}{l} \text{for 1 h, } R_{\rm S} + R_{\rm L} \geq 75~\Omega \\ \text{for 5 min, } R_{\rm S} + R_{\rm L} \geq 75~\Omega \end{array}$	
Supply current through protection device	$I_{\mathbb{S}}$	- 50	+ 50	mA		
Junction temperature	T_{j}	- - -	155 165 175 195	°C	for 2000 h (not additive) for 1000 h (not additive) for 168 h (not additive) for 3 x 1 h (additive)	
Storage temperature	$T_{\mathbb{S}}$	- 40	150	°C		
Magnetic flux density	В	_	unlimited	mT		

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 4 ESD Protection 1)

Parameter	Symbol	Limit	Values	Unit	Notes	
		min.	max.			
ESD voltage	V _{ESD}	_	± 8	kV	HBM, $R = 1.5 \text{ k}\Omega$, C = 100 pF $T_A = 25^{\circ}\text{C}$	

Human Body Model (HBM) tests according to: EOS/ESD Association Standard S5.1-1993 and Mil. Std. 883D method 3015.7



Operating Range

4 Operating Range

Table 5 Operating Range

Parameter	Symbol	Limit Values			Unit	Conditions
		min.	typ.	max.		
Supply voltage	V_{S}	3	_	18	V	
		3		24		for 5 min, $R_{\rm s}$ + $R_{\rm L}$ > 100 Ω
Junction temperature	T_{j}	- 40 -		150 175	°C	for 168 h



Electrical and Magnetic Parameters

5 Electrical and Magnetic Parameters

Table 6 Electrical Characteristics 1).

Parameter	Symbol	Limit Values			Unit	Conditions	
		min.	typ.	max.			
Supply current low	I_{SLOW}	5	6	7	mA	B > B _{RP} V _S = 3 V 18 V	
Supply current high	I_{SHiGH}	12	14	17	mA	B < B _{OP} V _S = 3 V 18 V	
Reverse current	I_{SR}	0	_	0.2	mA	V _S = - 18 V	
Output fall time	t_{f}	_	0.4	1.6	μs	$R_{\rm S}$ = 100 Ω , see:	
Output rise time	t_{r}	_	0.4	1.6	μs	Figure 3 "Timing Definition" on Page 12	
Chopper frequency	$f_{\sf OSC}$	-	320	-	kHz		
Switching freq.	$f_{\rm SW}$	0	_	15 ²⁾	kHz		
Delay time 3)	t_{d}	_	13	-	μs		
Output jitter 4)	$t_{\rm QJ}$	_	1	_	μs _{RMS}	Typical value for square wave signal 1 kHz	
Power-on time 5)	t_{PON}	_	13	_	μs	<i>V</i> _S ≥ 3.0 V	
Thermal resistance	R_{thJA}	-	100	-	K/W	SC59	
6)		_	_	190		PG-SSO-3-2	

- 1) over operating range, unless otherwise specified. Typical values correspond to VS =12 V and TA = 25°C
- 2) To operate the sensor at the max. switching frequency, the value of the magnetic signal amplitude must be 1.4 times higher than for static fields. This is due to the - 3 dB corner frequency of the low pass filter in the signal path.
- 3) Systematic delay between magnetic threshold reached and output switching
- 4) Jitter is the unpredictable deviation of the output switching delay
- 5) Time from applying $V_S \ge 2.7 \text{ V}$ to the sensor until the output state is valid
- 6) Thermal resistance from junction to ambient

Calculation of the ambient temperature (SC59 example)

e.g. for $V_{\rm S}$ = 12.0 V, $R_{\rm S}$ = 100 Ω , $I_{\rm SHIGHtyp}$ = 14 mA :

Power Dissipation: $P_{\rm DIS}$ = 148.4 mW.

In $T_A = T_j - (R_{thJA} \times PDIS) = 175^{\circ}C - (100 \text{ K/W} \times 0.15 \text{ W})$

Resulting max. ambient temperature: T_A = 160°C



Electrical and Magnetic Parameters

Table 7 Magnetic Characteristics TLE4976-1H and TLE4976L¹⁾

Parameter	Symbol	T_{j} [°C]	L	imit Valı	ues	Unit	Notes
			min.	typ.	max.		
Operate point	B_{OP}	- 40150	5.5	9.25	11.0	mT	TLE4976-1H
		- 40 25 150	1.1 1.0 0.9	4.1 4.0 3.8	6.1 6.0 5.8		TLE4976L
Release point	B_{RP}	- 40150	5.0	7.25	10.5	mT	TLE4976-1H
		- 40 25 150	3.1 3.0 2.9	6.1 6.0 5.8	8.2 8.0 7.7		TLE4976L
Hysteresis	B_{HYS}	- 40150	0.5	2	3	mT	TLE4976-1H
		- 40 25 150	- 0.5 -	- 2.0 -	- 3.5 -		TLE4976L
Temperature compensation	TC	_	_	0	-	ppm/°C	TLE4976-1H
of magnetic thresholds				- 200			TLE4976L
Repeatability of magnetic thresholds ²⁾	B_{REP}		_	40	_	μT _{RMS}	Typ. value for $\Delta B / \Delta t$ > 12 mT/ms

¹⁾ over operating range, unless otherwise specified. Typical values correspond to VS = 12 V.

Note: Typical characteristics specify mean values expected over the production spread.

Field Direction Definion

Positive magnetic fields related with south pole of magnet to the branded side of package.

²⁾ B_{RFP} is equivalent to the noise constant



Timing Diagram

6 Timing Diagram

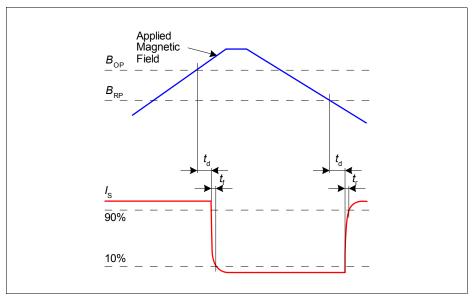


Figure 3 Timing Definition

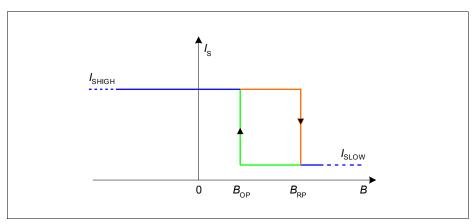


Figure 4 Output Signal



Application Circuit

7 Application Circuit

The advantage of the current interface is, that only two wires are necessary to connect the sensor.

At least one series resistor is required to convert the two output states of the Hall sensor from current consumption to a voltage information.

A typical value for $R_{\rm L}$ is 100 Ω . This gives a typical signal voltage level $V_{\rm SIG}$ of 0.8 V in the Off state and 1.4 V in the On state.

If the sensor is operated in an application environment with disturbances on the supply line, an additional series resistor $R_{\rm S}$ is recommended. The maximum value for the series resistor $R_{\rm S}$ can be calculated using the following formula:

$$R_{\text{Smax}} = \frac{V_{\text{Supplymin}} - V_{\text{Smin}}}{I_{\text{Shighmax}}} - R_{\text{L}}$$

 $V_{\rm S_min}$ is the minimal supply voltage which might occur due to disturbances on the supply line $V_{\rm S}$.

Example:
$$V_{\rm Supplymin}$$
 = 6 V; $V_{\rm Smin}$ = 3 V; $R_{\rm L}$ = 100 Ω ; $I_{\rm Shighmax}$ = 17 mA : $R_{\rm Smax}$ = 76.5 Ω

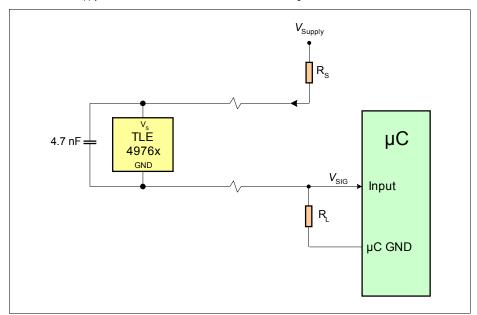


Figure 5 Application Circuitl

Data Sheet 13 V 1.1. 2005-10



8 Package Information

8.1 Package Marking

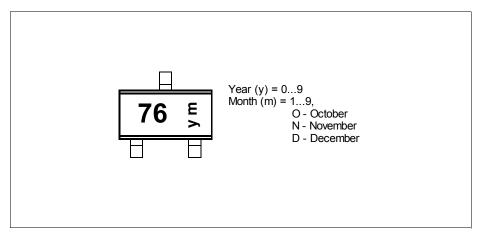


Figure 6 Marking TLE4976-1H

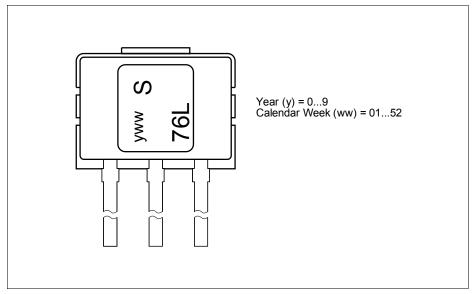


Figure 7 Marking TLE4976L



8.2 Distance between Chip and Package Surface

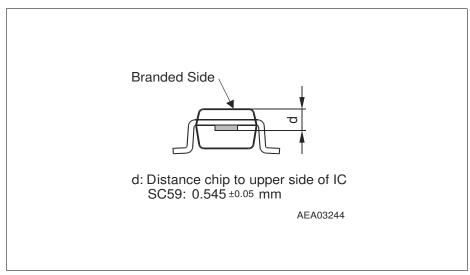


Figure 8 Distance Chip SC59 to Upper Side of IC

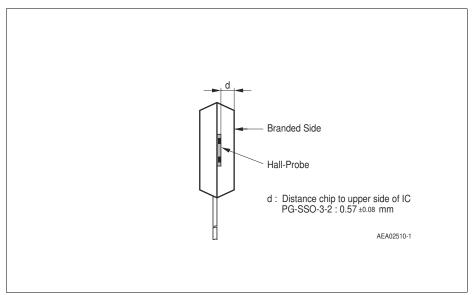


Figure 9 Distance Chip PG-SSO-3-2 to Upper Side of IC



8.3 Package Outlines

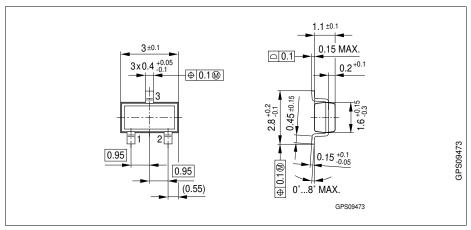


Figure 10 SC59

PCB Footprint for SC59

The following picture shows a recommendation for the PCB layout.

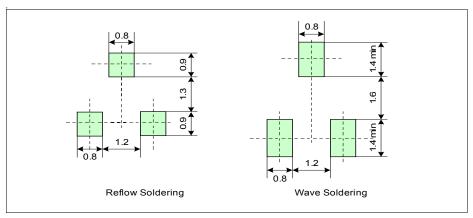


Figure 11 Footprint SC59 (SOT23 compatible)



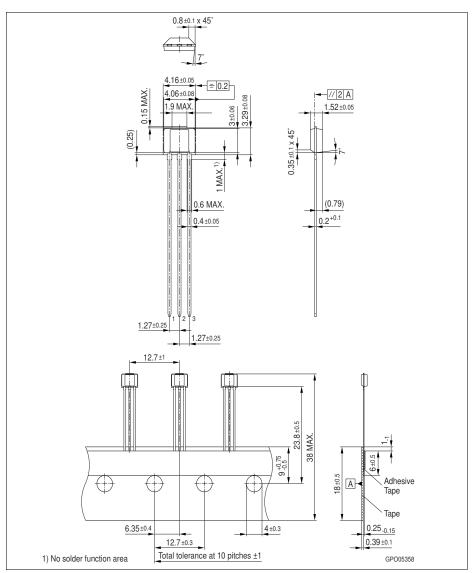


Figure 12 PG-SSO-3-2

Note: You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.

Dimensions in mm



Notes



Notes

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